

# RJH65T46DPQ-A0

650V - 40A - IGBT Application: Power Factor Correction circuit R07DS1259EJ0100 Rev.1.00 May 18, 2015

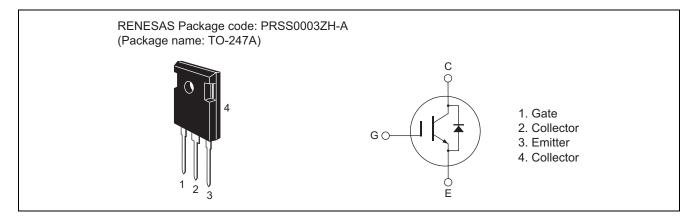
#### **Features**

- Low collector to emitter saturation voltage
   V<sub>CE(sat)</sub> = 1.8 V typ. (at I<sub>C</sub> = 40 A, V<sub>GE</sub> = 15 V, Ta = 25°C)
- Built in fast recovery diode in one package
- Trench gate and thin wafer technology (G7H series)
- High speed switching

 $t_f = 45 \text{ ns typ.}$  (at  $V_{CC} = 400 \text{ V}$ ,  $V_{GE} = 15 \text{ V}$ ,  $I_C = 40 \text{ A}$ ,  $Rg = 10 \Omega$ ,  $Ta = 25^{\circ}C$ , Inductive load)

- Operation frequency  $(20kHz \le f < 100kHz)$
- Not guarantee short circuit withstand time

#### **Outline**



### **Absolute Maximum Ratings**

 $(Tc = 25^{\circ}C)$ 

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V <sub>CES</sub> / V <sub>R</sub>	650	V
Gate to emitter voltage		V <sub>GES</sub>	±30	V
Collector current	Tc = 25 °C	Ic	80	Α
	Tc = 100 °C	lc	40	Α
Collector peak current		ic(peak) Note1	300	Α
Collector to emitter diode	Tc = 25 °C	I <sub>DF</sub>	30	Α
Forward current	Tc = 100 °C	IDF	15	Α
Collector to emitter diode forward peak current		i <sub>DF</sub> (peak) Note1	100	Α
Collector dissipation		Pc	340.9	W
Junction to case thermal impedance (IGBT)		θј-с	0.44	°C/W
Junction to case thermal resistance (Diode)		θj-cd	1.33	°C/W
Junction temperature		Tj Note2	175	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Please use this device in the thermal conditions which the junction temperature does not exceed 175°C. Renesas IGBT Application Note is disclosed about reliability test and application condition up to 175°C.

### **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current / Diode reverse current	I <sub>CES</sub> / I <sub>R</sub>	_	_	100	μΑ	$V_{CE} = 650 \text{ V}, V_{GE} = 0$	
Gate to emitter leak current	Iges	_	_	±1	μΑ	V <sub>GE</sub> = ±30 V, V <sub>CE</sub> = 0	
Gate to emitter cutoff voltage	V <sub>GE(off)</sub>	4.0	_	7.0	V	$V_{CE} = 10V, I_{C} = 1.33 \text{ mA}$	
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	1.8	2.4	V	Ic = 40 A, V <sub>GE</sub> = 15V Note3	
Input capacitance	Cies	_	3000	_	pF	V <sub>CE</sub> = 25 V V <sub>GE</sub> = 0 f = 1 MHz	
Output capacitance	Coes	_	92	_	pF		
Reveres transfer capacitance	Cres	_	55	_	pF		
Total gate charge	Qg	_	138	_	nC	VGE = 15 V VCE = 400 V	
Gate to emitter charge	Qge	_	22	_	nC		
Gate to collector charge	Qgc	_	57	_	nC	IC = 40 A	
Turn-on delay time	t <sub>d(on)</sub>	_	45	_	ns	Vcc = 400 V	
Rise time	tr	_	30	_	ns	V <sub>GE</sub> = 15 V	
urn-off delay time	t <sub>d(off)</sub>	_	170	_	ns	Ic = 40 A Rg = 10 $\Omega$ T <sub>C</sub> = 25 °C Inductive load Note4	
Fall time	t <sub>f</sub>	_	45	_	ns		
Turn-on loss energy	Eon	_	0.45	_	mJ		
Turn-off loss energy	E <sub>off</sub>	_	0.55	_	mJ	Inductive load	
Total switching energy	E <sub>total</sub>	_	1.00	_	mJ		
Turn-on delay time	t <sub>d(on)</sub>	_	45	_	ns	V <sub>CC</sub> = 400 V V <sub>GE</sub> = 15 V I <sub>C</sub> = 40 A	
Rise time	tr	_	30	_	ns		
Turn-off delay time	t <sub>d(off)</sub>	_	185	_	ns		
Fall time	t <sub>f</sub>		50	_	ns	$Rg = 10 \Omega$	
Turn-on loss energy	Eon	_	0.57	_	mJ	T <sub>C</sub> = 150 °C Inductive load <sup>Note4</sup>	
Turn-off loss energy	E <sub>off</sub>	_	0.63	_	mJ	THUUCHVE IOAU	
Total switching energy	E <sub>total</sub>	_	1.20	_	mJ		
FRD forward voltage	VF		1.7	2.2	V	I <sub>F</sub> = 15 A <sup>Note3</sup>	
1 ND 101 Ward Voltage	٧F		1.7	۷.۷	V	1F = 10 / L	

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Notes: 3. Pulse test

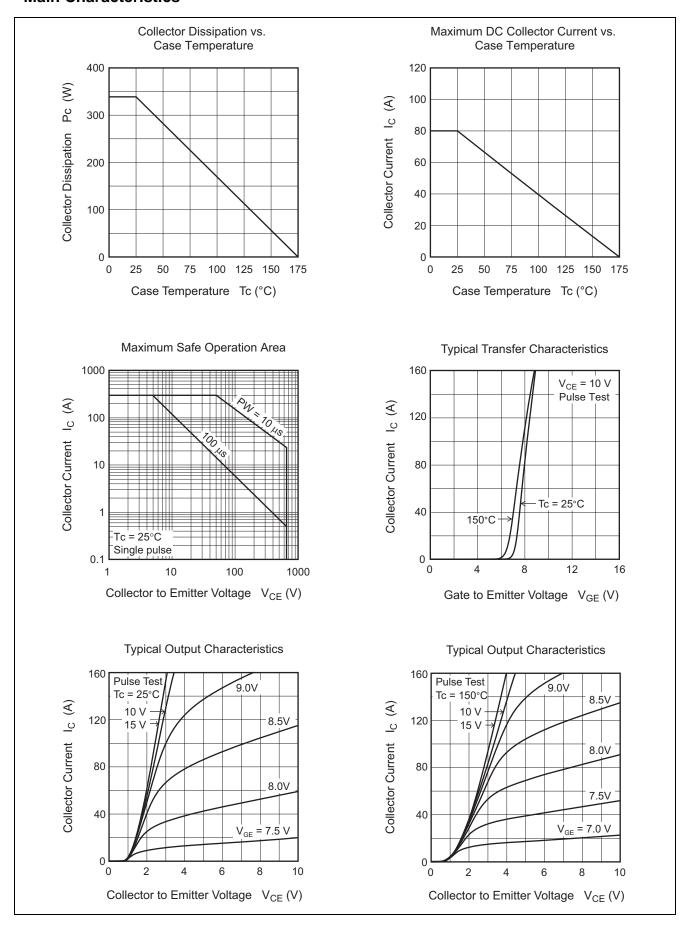
FRD reverse recovery time

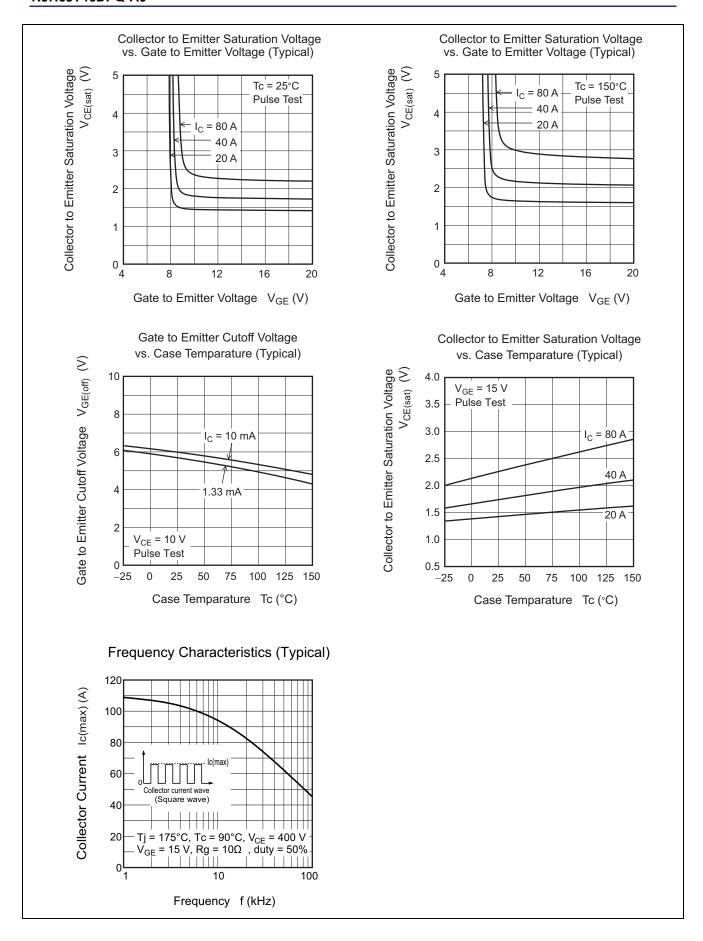
4. Switching time test circuit and waveform are shown below.

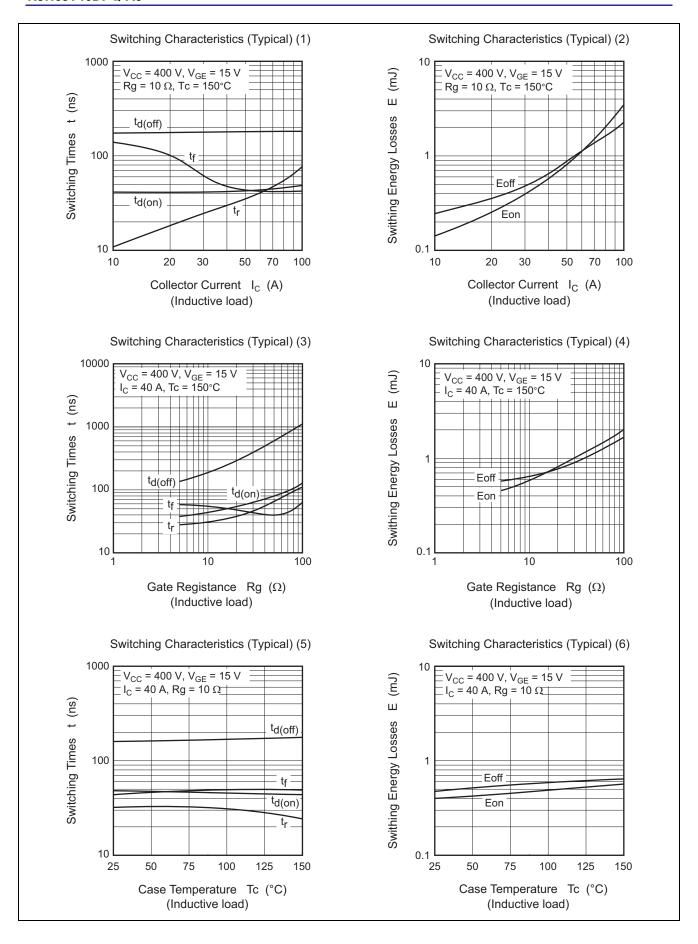
 $I_F = 15 \text{ A}, \text{ dir/dt} = 300 \text{ A/}\mu\text{s}$ 

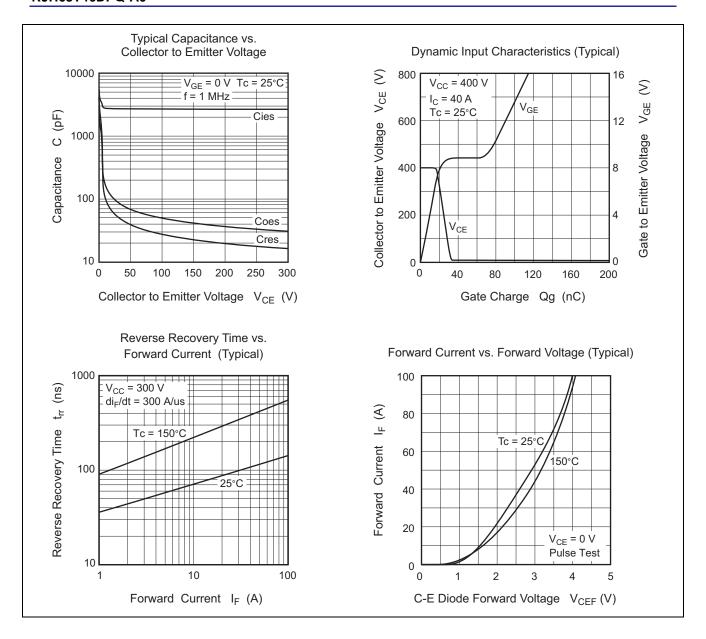
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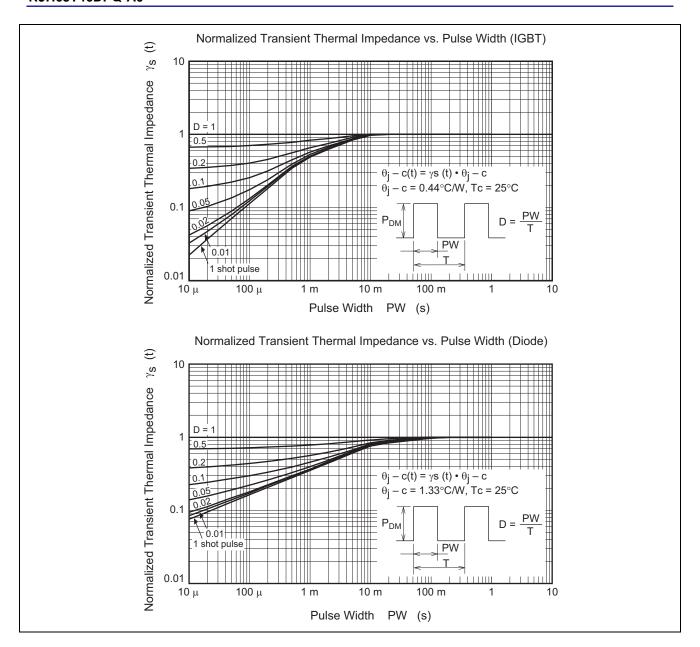
#### **Main Characteristics**

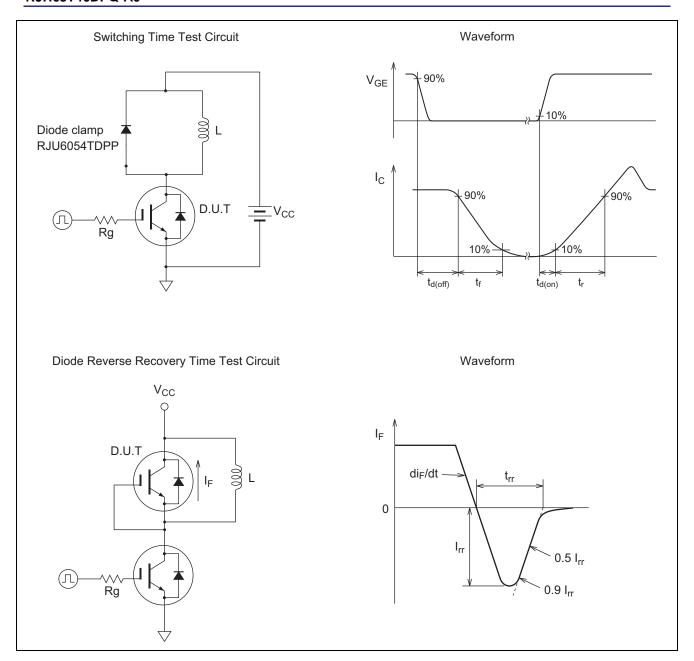




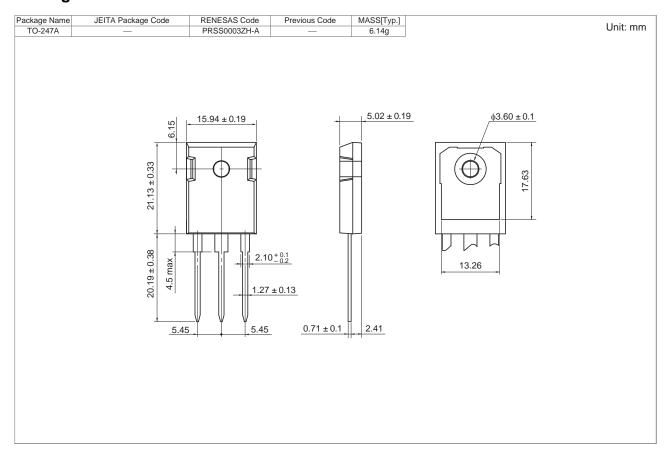








### **Package Dimensions**



### **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJH65T46DPQ-A0#T0	240 pcs	Box (Tube)

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